Surface Mount Schottky Power Rectifier

SOD-123 Power Surface Mount Package

The Schottky Power Rectifier employs the Schottky Barrier principle with a barrier metal that produces optimal forward voltage drop-reverse current tradeoff. Ideally suited for low voltage, high frequency rectification, or as a free wheeling and polarity protection diodes in surface mount applications where compact size and weight are critical to the system. This package provides an alternative to the leadless 34 MELF style package.

Features

- Guardring for Stress Protection
- Very Low Forward Voltage
- Epoxy Meets UL 94 V-0 @ 0.125 in
- Package Designed for Optimal Automated Board Assembly
- Pb–Free Packages are Available

Mechanical Characteristics

- Reel Options: 3,000 per 7 inch reel/8 mm tape
- Reel Options: 10,000 per 13 inch reel/8 mm tape
- Device Marking: B4
- Polarity Designator: Cathode Band
- Weight: 11.7 mg (approximately)
- Case: Epoxy Molded
- Finish: All External Surfaces Corrosion Resistant and Terminal Leads are Readily Solderable
- Lead and Mounting Surface Temperature for Soldering Purposes: 260°C max. for 10 Seconds



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SCHOTTKY BARRIER RECTIFIER 0.5 AMPERES, 40 VOLTS



SOD-123 CASE 425 STYLE 1

MARKING DIAGRAM



B4 = Device Code

- M = Date Code
- = Pb–Free Package

(Note: Microdot may be in either location)

ORDERING INFORMATION

| Device | Package | Shipping [†] |
|------------|----------------------|-----------------------|
| MBR0540T1 | SOD-123 | 3000/Tape & Reel |
| MBR0540T1G | SOD-123 (Pb-Free) | 3000/Tape & Reel |
| MBR0540T3 | SOD-123 | 10,000/Tape & Reel |
| MBR0540T3G | SOD-123 (Pb-Free) | 10,000/Tape & Reel |

+For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specifications Brochure, BRD8011/D.

MAXIMUM RATINGS

| Rating | Symbol | Value | Unit V |
|--|--|--------------------|-----------|
| Peak Repetitive Reverse Voltage Working Peak Reverse Voltage DC Blocking Voltage | V _{RRM} V _{RWM} V _R | 40 | |
| Average Rectified Forward Current (At Rated V_R , T_C = 115°C) | Io | I _O 0.5 | |
| Peak Repetitive Forward Current (At Rated V_R , Square Wave, 20 kHz, T_C = 115°C) | I _{FRM} | 1.0 | A |
| Non–Repetitive Peak Surge Current (Surge Applied at Rated Load Conditions Halfwave, Single Phase, 60 Hz) | I _{FSM} | 5.5 | A |
| Storage/Operating Case Temperature Range | T _{stg} , T _C | | |
| Operating Junction Temperature | TJ | -55 to +150 | °C |
| Voltage Rate of Change (Rated V_R , $T_J = 25^{\circ}C$) | dv/dt | 1000 | V/µs |

Maximum ratings are those values beyond which device damage can occur. Maximum ratings applied to the device are individual stress limit values (not normal operating conditions) and are not valid simultaneously. If these limits are exceeded, device functional operation is not implied, damage may occur and reliability may be affected.

THERMAL CHARACTERISTICS

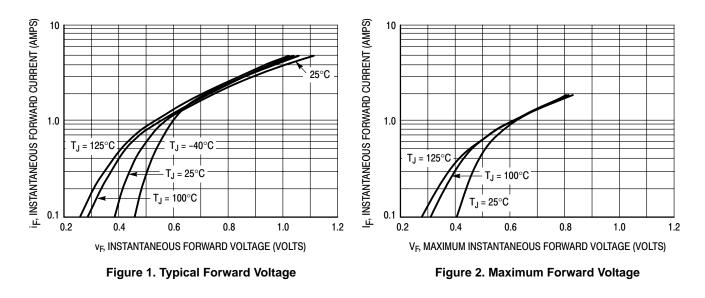
| Rating | Symbol | Value | Unit |
|---|------------------|-------|------|
| Thermal Resistance – Junction–to–Lead (Note 1) | R _{tjl} | 118 | °C/W |
| Thermal Resistance – Junction–to–Ambient (Note 2) | R _{tja} | 206 | |

ELECTRICAL CHARACTERISTICS

| Maximum Instantaneous Forward Voltage (Note 3) | ٧F | T _J = 25°C | T _J = 100°C | V |
|--|----------------|-----------------------|------------------------|----|
| (i _F = 0.5 A) (i _F = 1 A) | | 0.51 0.62 | 0.46 0.61 | |
| Maximum Instantaneous Reverse Current (Note 3) | ۱ _R | $T_J = 25^{\circ}C$ | T _J = 100°C | μΑ |
| (V _R = 40 V) (V _R = 20 V) | | 20 10 | 13,000 5,000 | |

1. Mounted with minimum recommended pad size, PC Board FR4.

2. 1 inch square pad size (1 X 0.5 inch for each lead) on FR4 board. 3. Pulse Test: Pulse Width \leq 250 µs, Duty Cycle \leq 2.0%.



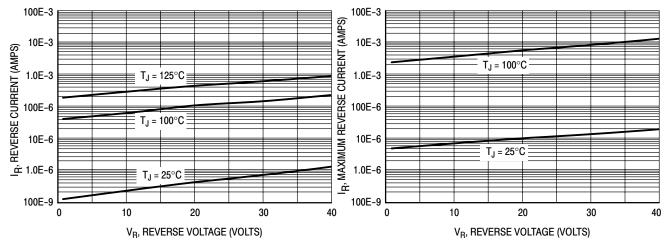
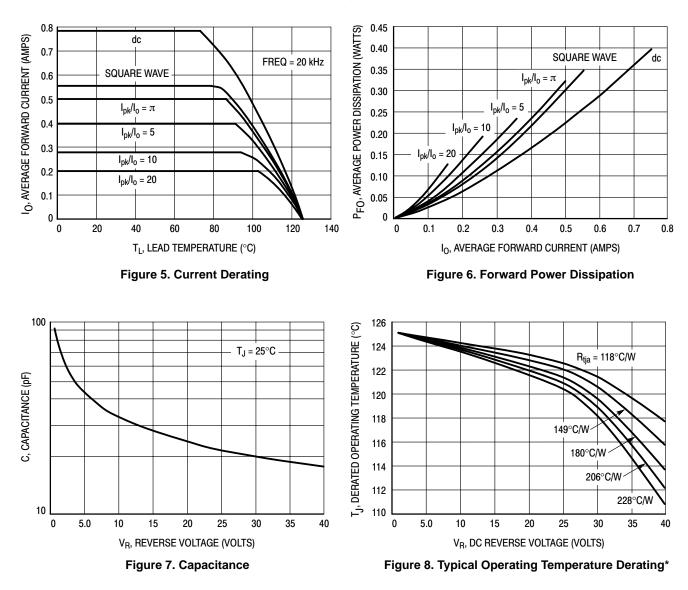


Figure 3. Typical Reverse Current

Figure 4. Maximum Reverse Current



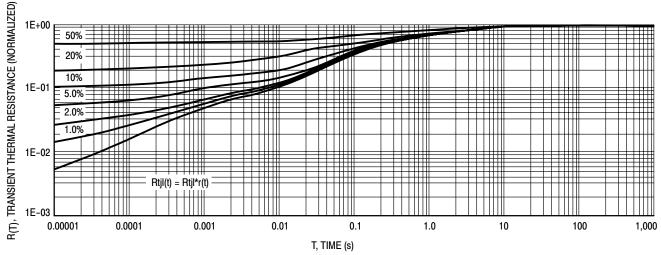
* Reverse power dissipation and the possibility of thermal runaway must be considered when operating this device under any reverse voltage conditions. Calculations of T_J therefore must include forward and reverse power effects. The allowable operating T_J may be calculated from the equation: $T_J = T_{Jmax} - r(t)(Pf + Pr)$ where

r(t) = thermal impedance under given conditions,

Pf = forward power dissipation, and

Pr = reverse power dissipation

This graph displays the derated allowable T_J due to reverse bias under DC conditions only and is calculated as $T_J = T_{Jmax} - r(t)Pr$, where r(t) = Rthja. For other power applications further calculations must be performed.





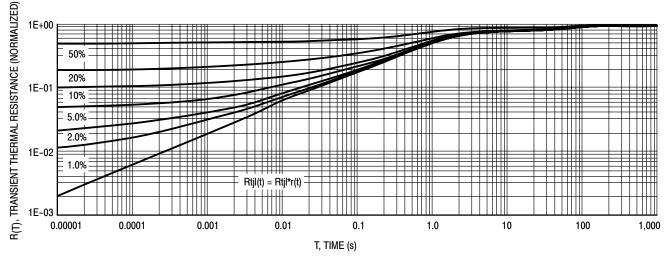
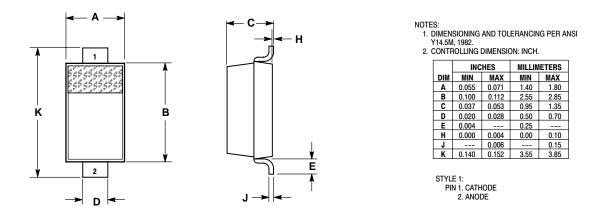


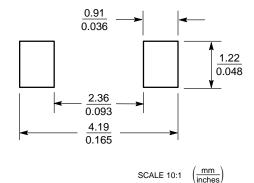
Figure 10. Thermal Response Junction to Ambient

PACKAGE DIMENSIONS

SOD-123 PLASTIC CASE 425-04 ISSUE C



SOLDERING FOOTPRINT*



*For additional information on our Pb–Free strategy and soldering details, please download the ON Semiconductor Soldering and Mounting Techniques Reference Manual, SOLDERRM/D.

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